

1110-97825 PATENT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Appl. No.	: 10/586,445	)	Confirmation No.: To be assigned
Applicant	: INAGAKI et al.	)	
Filed	: 27 January 2005	)	
Art Unit	: To be assigned	)	
Examiner	: To be assigned	)	
Docket No.	: 1110-97825	)	
Customer No.:	24628	)	
Title: METHOD FOR PREDICTING			
PRECIPITATION BEHAVIOR OF OXYGEN			
IN SILICON SINGLE CRYSTAL, METHOD			
FOR DETERMINING PRODUCTION			
PARAMETER OF SILICON SINGLE			
CRYSTAL, AND STORAGE MEDIUM FOR			
STORING PROGRAM FOR PREDICTING			
PRECIPITATION BEHAVIOR OF OXYGEN			
IN SILICON SINGLE CRYSTAL			

Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

**CORRECTION**

Dear Sir:

We submit the following corrected TRANSMITTAL LETTER TO THE UNITED STATES DESIGNATED/ELECTED OFFICE (DO/EO/US) CONCERNING A SUBMISSION UNDER 35 U.S.C. 371 to correct unintentional defects in the transmittal letter. No new material has been added through the submission of these corrections.

Respectfully submitted,



Dated: 20 February 2009

**Gerald T Shekleton**

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